

T493B226M010BH6110

Aliases (DLA Drawing 07016-033MBHZ)

General Information

Series

Dielectric Style

Description

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 22 uF, 20%, 10 VDC, SMD, MnO2, Molded, DLA Drawing, B (0.1%/1000 Hrs), 3 Ohms, 3528, 2.1 mm,

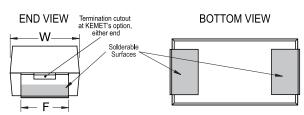
T493 HRA

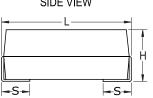
SMD Chip

Drawing

MnO2 Tantalum

SMD, MnO2, Molded, DLA





Di

Packaging Quantity

SIDE VIEW H Click here for the 3D model.		
	RoHS	No
	Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov / .
	SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9 d519011aa
	Termination	Tin Lead (SnPb)
	AEC-Q200	No
	Typical Component Weight	102.3 mg
imensions	Specifications	
3.5mm +/-0.2mm	Capacitance	22 uF

L	3.5mm +/-0.2mm	
W	2.8mm +/-0.2mm	
Н	1.9mm +/-0.2mm	
S	0.8mm +/-0.3mm	
F	2.2mm +/-0.1mm	
Packaging Specifications		
Packaging	T&R, 178mm	

2000

Specifications	
Capacitance	22 uF
Tolerance	20%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	3 Ohms (100kHz 25C)
Ripple Current	348 mA (rms, 100kHz 25C)
Leakage Current	2.2 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

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